



Product Specifications

PART NO:

VL366S1723-GAS

REV: 1.1

General Information

128MB 16Mx64 SDRAM PC133 UNBUFFERED 168 PIN DIMM

Description: The VL366S1723 is a 16M X 64 Synchronous Dynamic RAM high density memory module. This memory module consists of eight CMOS 16Mx8 bits with 4 banks Synchronous DRAMs in TSOP-II 400mil packages and a 2K EEPROM in 8-pin TSSOP package. This module is a 168-pin Dual In-line Memory Module and is intended for mounting into connector sockets. Decoupling capacitors are mounted on the printed circuit board for each SDRAM.

Features:

- Unbuffered 8 byte SDRAM 168pin DIMM
- High Speed - 133MHz, CL3
- Burst Mode Operation
- Auto & Self refresh Capability (4096 Cycles/64ms)
- LVTTTL compatible inputs and outputs
- Single 3.3V ± 0.3 V power supply
- 12/10/4 Addressing (Row/Column/Bank)
- MRS cycle with address key programs
- EPROM Serial Presence Detect
- Gold (Au) contacts
- Lead-free/RoHS compliant
- PCB height: **1150 (mil)**, single sided component

Pin Name	Function
A0-A11	Address inputs
BA0, BA1	Bank Select Address
DQ0-DQ63	Data Input/Output
CLK0, CLK1, CLK2, CLK3	Clock Input
CKE0	Clock Enable Input
CS0#, CS2#	Chip Select Input
RAS#	Row Address Strobe
CAS#	Column Address Input
WE#	Write Enable
DQM0-DQM7	Data input/output mask
VDD	Power Supply (3.3V)
VSS	Ground
*VREF	Power Supply for Reference
SDA	Serial Data Input/Output
SCL	SPD Clock Input
SA0 - SA2	Address in EEPROM
NC	No Connect

* These pins are not used in this module.

Order Information:

VL366S1723-GA S

DRAM MANUFACTURER
S - SAMSUNG

MODULE SPEED
GA: PC133 @ CL3

VL: Lead-free/RoHS



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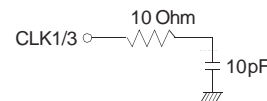
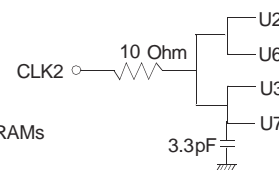
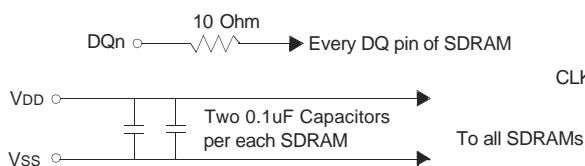
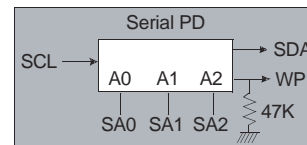
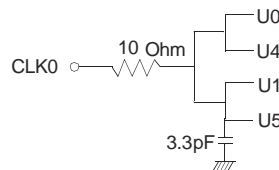
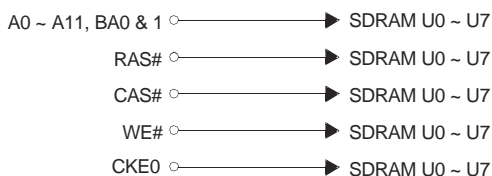
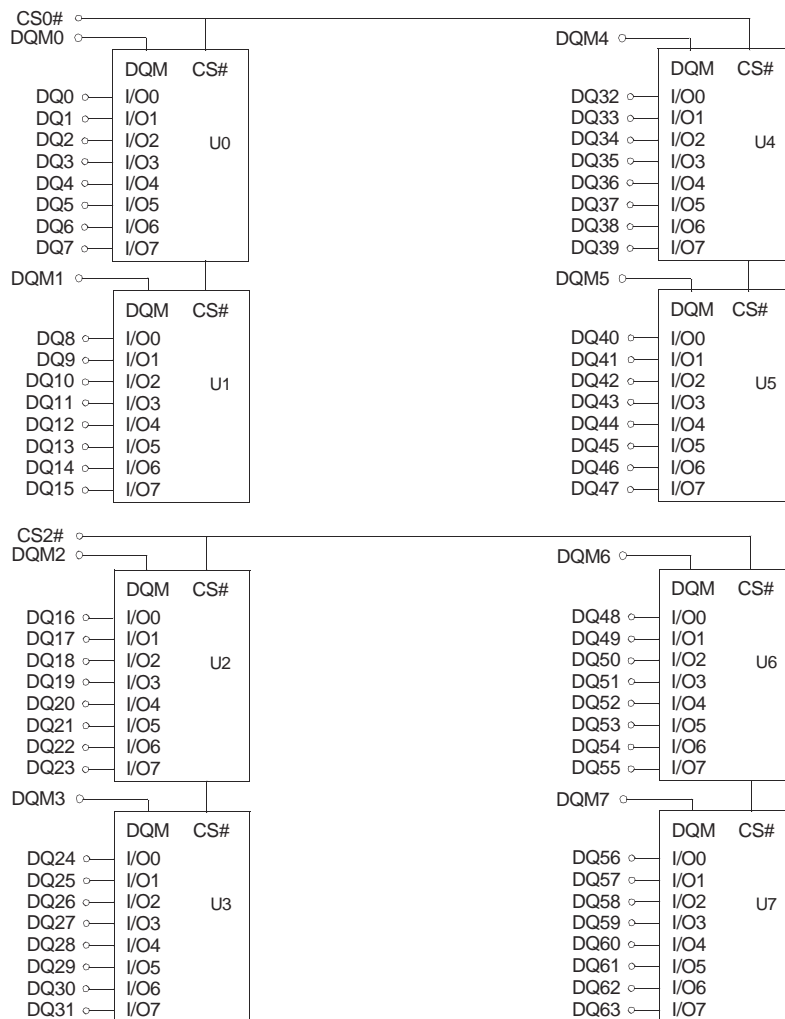
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Pin Configuration

Pin Number	Front Side	Pin Number	Front Side	Pin Number	Back Side	Pin Number	Back Side
1	V _{SS}	43	V _{SS}	85	V _{SS}	127	V _{SS}
2	DQ0	44	NC	86	DQ32	128	CKE0
3	DQ1	45	CS2#	87	DQ33	129	NC
4	DQ2	46	DQM2	88	DQ34	130	DQM6
5	DQ3	47	DQM3	89	DQ35	131	DQM7
6	V _{DD}	48	NC	90	V _{DD}	132	NC
7	DQ4	49	V _{DD}	91	DQ36	133	V _{DD}
8	DQ5	50	NC	92	DQ37	134	NC
9	DQ6	51	NC	93	DQ38	135	NC
10	DQ7	52	NC	94	DQ39	136	NC
11	DQ8	53	NC	95	DQ40	137	NC
12	V _{SS}	54	V _{SS}	96	V _{SS}	138	V _{SS}
13	DQ9	55	DQ16	97	DQ41	139	DQ48
14	DQ10	56	DQ17	98	DQ42	140	DQ49
15	DQ11	57	DQ18	99	DQ43	141	DQ50
16	DQ12	58	DQ19	100	DQ44	142	DQ51
17	DQ13	59	V _{DD}	101	DQ45	143	V _{DD}
18	V _{DD}	60	DQ20	102	V _{DD}	144	DQ52
19	DQ14	61	NC	103	DQ46	145	NC
20	DQ15	62	NC	104	DQ47	146	NC
21	NC	63	NC	105	NC	147	NC
22	NC	64	V _{SS}	106	NC	148	V _{SS}
23	V _{SS}	65	DQ21	107	V _{SS}	149	DQ53
24	NC	66	DQ22	108	NC	150	DQ54
25	NC	67	DQ23	109	NC	151	DQ55
26	V _{DD}	68	V _{SS}	110	V _{DD}	152	V _{SS}
27	WE#	69	DQ24	111	CAS#	153	DQ56
28	DQM0	70	DQ25	112	DQM4	154	DQ57
29	DQM1	71	DQ26	113	DQM5	155	DQ58
30	CS0#	72	DQ27	114	NC	156	DQ59
31	NC	73	V _{DD}	115	RAS#	157	V _{DD}
32	V _{SS}	74	DQ28	116	V _{SS}	158	DQ60
33	A0	75	DQ29	117	A1	159	DQ61
34	A2	76	DQ30	118	A3	160	DQ62
35	A4	77	DQ31	119	A5	161	DQ63
36	A6	78	V _{SS}	120	A7	162	V _{SS}
37	A8	79	CLK2	121	A9	163	CLK3
38	A10/AP	80	NC	122	BA0	164	NC
39	BA1	81	NC	123	A11	165	SA0
40	V _{DD}	82	SDA	124	V _{DD}	166	SA1
41	V _{DD}	83	SCL	125	CLK1	167	SA2
42	CLK0	84	V _{DD}	126	NC	168	V _{DD}

Functional Block Diagram





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Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Voltage on any pin relative to V _{SS}	V _{IN} , V _{OUT}	-1.0 ~ 4.6	V
Voltage on V _{DD} supply relative to V _{SS}	V _{DD} , V _{DDQ}	-1.0 ~ 4.6	V
Storage temperature	T _{STG}	-55 ~ +150	°C
Power dissipation	P _D	8	W
Short circuit current	I _{OS}	50	mA

Note: Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded. Functional operation should be restricted to recommended operating condition. Exposure to higher than recommended voltage for extended periods of time could affect device reliability.

Recommended DC Operating Conditions (T_A = 0°C to +70°C)

Parameter	Symbol	Min	Typ	Max	Unit	Note
Supply voltage	V _{DD} , V _{DDQ}	3.0	3.3	3.6	V	
Input high voltage	V _{IH}	2.0	3.0	V _{DDQ} +0.3	V	1
Input low voltage	V _{IL}	-0.3	0	0.8	V	2
Output high voltage	V _{OH}	2.4	-	-	V	I _{OH} = -2mA
Output low voltage	V _{OL}	-	-	0.4	V	I _{OL} = 2mA
Input leakage current (Inputs)	I _{IL}	-18	-	18	uA	3
Input leakage current (I/O pins)	I _{IL}	-3	-	3	uA	3,4

Notes: 1. V_{IH} (max) = 5.6V AC. The overshoot voltage duration is <= 3ns.
 2. V_{IL} (min) = 2.0V AC. The undershoot voltage duration is <= 3ns.
 3. Any input 0V <= V_{IN} <= V_{DDQ}.
 4. DOUT is disabled, 0V <= V_{OUT} <= V_{DDQ}.

Capacitance (T_A = 25°C, f = 1MHz, V_{DD} = 3.3V)

Parameter	Symbol	Min	Max	Unit
Input capacitance (A0 ~ A11, BA0 ~ BA1)	C _{IN1}	25	45	pF
Input capacitance (RAS#, CAS#, WE#)	C _{IN2}	25	45	pF
Input capacitance (CKE0)	C _{IN3}	25	45	pF
Input capacitance (CLK0, CLK2)	C _{IN4}	15	21	pF
Input capacitance (CS0#, CS2#)	C _{IN5}	15	25	pF
Input capacitance (DQM0 ~ DQM7)	C _{IN6}	8	12	pF
Data input/output capacitance (DQ0 ~ DQ63)	C _{OUT}	9	12	pF



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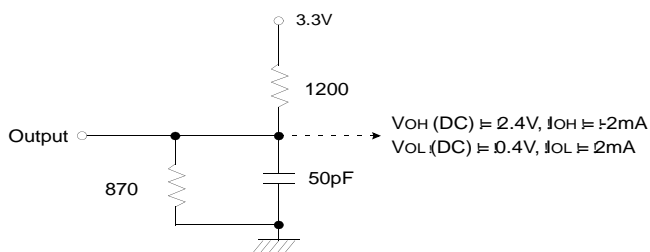
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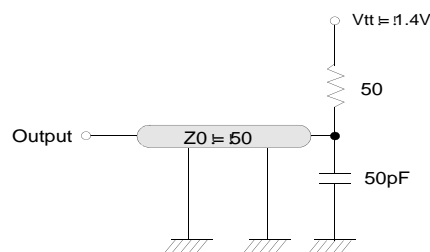
DC Characteristics (Recommended operation condition unless otherwise noted, TA = 0°C to +70°C)					
Parameter	Symbol	Test Condon	Version	Unit	Note
			-GA		
Operating current (One bank active)	Icc1	Burst length = 1 trc >= trc(min) IOL = 0 mA	720	mA	1
Precharge standby current in power-down mode	Icc2P	CKE <= VIL(max), tcc = 10ns	16	mA	
	Icc2PS	CKE & CLK <= VIL(max), tcc = ∞	16	mA	
Precharge standby current in non power-down mode	Icc2N	CKE >= VIH (min), CS# >= VIH (min), tcc = 10ns Input signals are changed one time during 20ns	160	mA	
	Icc2NS	CKE >= VIH(min), CLK <= VIL(max), tcc = ∞ Input signals are stable	80	mA	
Active standby current in power-down mode	Icc3P	CKE <= VIL(max), tcc = 10ns	40	mA	
	Icc3PS	CKE & CLK <= VIL(max), tcc = ∞	40	mA	
Active standby current in non power-down mode (One bank active)	Icc3N	CKE >= VIH(min), CS# >= VIH(min), tcc = 10ns Input signals are changed one time during 20ns	240	mA	
	Icc3NS	CKE >= VIH(min), CLK <= VIL (max), tcc = ∞ Input signals are stable	200	mA	
Operating current (Burst mode)	Icc4	IOL = 0 mA Page burst 2 Banks actived tccd = 2CLKs	880	mA	1
Refresh current	Icc5	trc >= trc(min)	1600	mA	2
Self refresh current	Icc6	CKE <= 0.2V	16	mA	
Note: 1. Measured with outputs open. 2.Refresh period is 64ms.					

AC Operating Test Conditions (VDD = 3.3V, TA = 0°C to +70°C)

Parameter	Value	Unit
AC input levels (V _H /V _L)	2.4/0.4	V
Input timing measurement reference level	1.4	V
Input rise and fall time	tr/tf = 1/1	ns
Output timing measurement reference level	1.4	V
Output load condition	See Fig.2	



(Fig. 1) DC output load circuit!



(Fig. 2) AC output load circuit!

Operating AC Parameter

Parameter	Symbol	Version	Unit	Note
		-GA		
Row active to row active delay	t _{RRD} (min)	15	ns	1
RAS# to CAS# delay	t _{RCD} (min)	20	ns	1
Row precharge time	t _{RP} (min)	20	ns	1
Row active time	t _{RAS} (min)	45	ns	1
	t _{RAS} (max)	100	us	
Row cycle time	t _{RC} (min)	65	ns	1
Last data in to row precharge	t _{RDL} (min)	2	CLK	2
Last data in to Active delay	t _{DAL} (min)	2 CLK + t _{RP}	-	
Last data in to new col. address delay	t _{CDL} (min)	1	CLK	1
Last data in to burst stop	t _{BDL} (min)	1	CLK	2
Col. address to col. address delay	t _{CCD} (min)	1	CLK	2
Number of valid output data	CAS Latency = 3	2	CLK	3
	CAS Latency = 2	1	ea	4

Notes: 1. The minimum number of clock cycles is determined by dividing the minimum time required with clock cycle time and then rounding off to the next higher integer.
 2. Minimum delay is required to complete write.
 3. All parts allow every cycle column address change.
 4. In case of row precharge interrupt, auto precharge and read burst stop.



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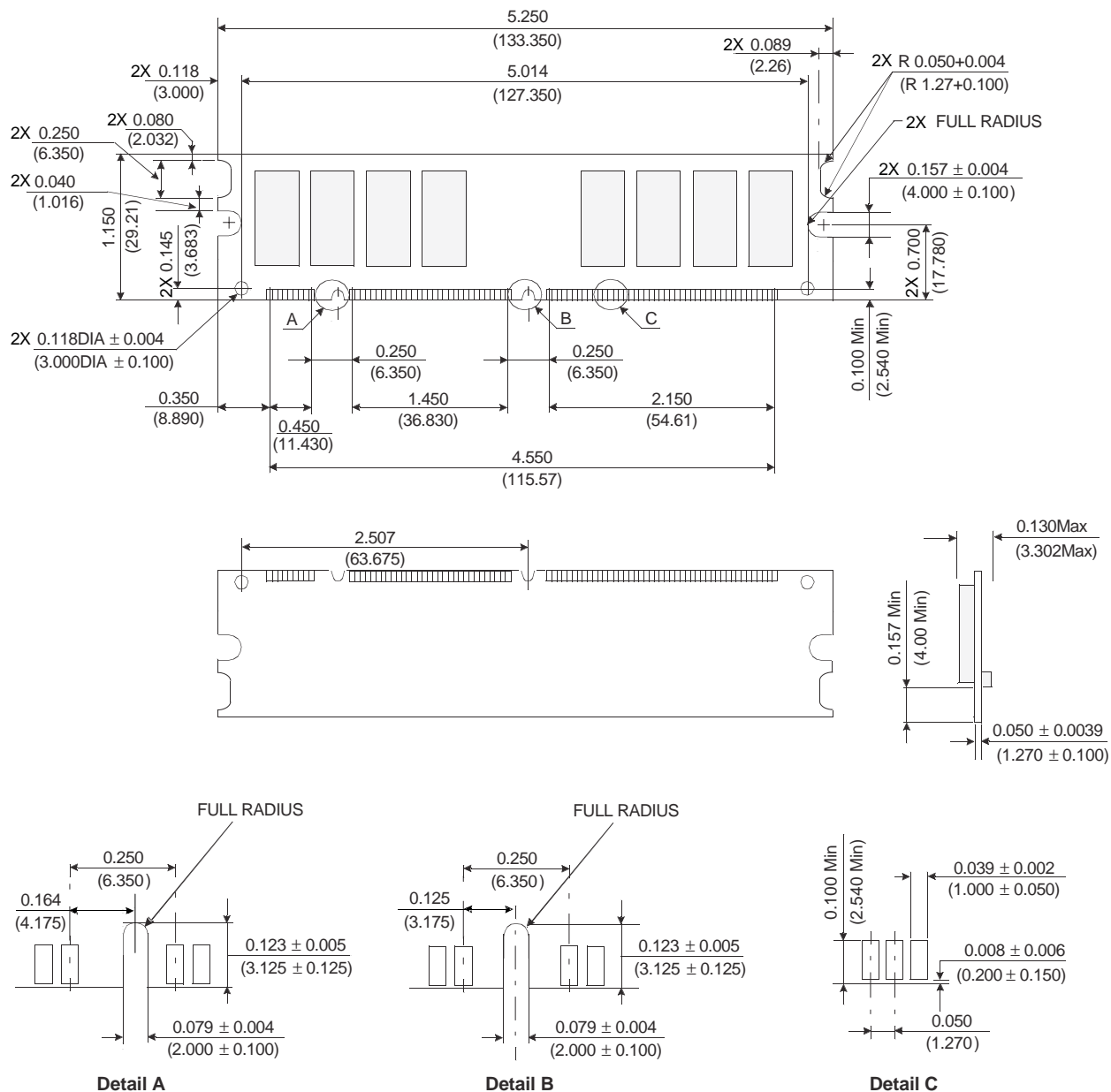
Operating AC Parameter

Parameter	Symbol	-GA		Unit	Note	
		Min	Max			
CLK cycle time	CAS latency = 3	tcc	7.5	1000	ns	1
	CAS latency = 2		-			
CLK to valid output delay	CAS latency = 3	tsac		5.4	ns	1,2
	CAS latency = 2			-		
Output data hold time	CAS latency = 3	toH	3		ns	2
	CAS latency = 2			-		
CLK high pulse width		tch	2.5		ns	3
CLK low pulse width		tcl	2.5		ns	3
Input setup time		tss	1.5		ns	3
Input hold time		tsh	0.8		ns	3
CLK to output in Low-Z		tslz	1		ns	2
CLK to output in Hi-z	CAS latency = 3	tshz		5.4	ns	
	CAS latency = 2			-		

Notes: 1. Parameters depend on programmed CAS latency.
 2. If clock rising time is longer than 1ns, (tr/2-0.5)ns should be added to the parameter.
 3. Assumed input rise and fall time (tr & tf) = 1ns.
 if tr & tf is longer than 1ns, transient timecompensation should be considered,
 i.e. ,[(tr + tf)/2-1]ns should be added to the parameter.

Package Dimensions

Units : Inches (Millimeters)



Tolerances : ± .005(.13) unless otherwise specified



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Revision History:

Date	Rev.	Page	Changes
06/18/08	1.0	All	Released Spec
09/24/10	1.1	All	Update datasheet